

Hongyan Yu

List of Publications by Year in descending order

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22
papers

100
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1684188
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g-index

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22
times ranked

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citing authors

#	ARTICLE	IF	CITATIONS
1	Hybrid InGaAsP-Si Evanescent Laser by Selective-Area Metal-Bonding Method. <i>IEEE Photonics Technology Letters</i> , 2013, 25, 1180-1183.	2.5	23
2	4- μ m InGaAsP-Si distributed feedback evanescent lasers with varying silicon waveguide width. <i>Optics Express</i> , 2014, 22, 5448.	3.4	21
3	A Buried Ridge Stripe Structure InGaAsP-Si Hybrid Laser. <i>IEEE Photonics Technology Letters</i> , 2015, 27, 352-355.	2.5	14
4	A GaAs-Based Hybrid Integration of a Tunneling Diode and a 1060-nm Semiconductor Laser. <i>IEEE Photonics Technology Letters</i> , 2015, 27, 169-172.	2.5	9
5	Demonstration of 128-Channel Optical Phased Array With Large Scanning Range. <i>IEEE Photonics Journal</i> , 2021, 13, 1-10.	2.0	8
6	Monolithic integration of InGaAs/InP multiple quantum wells on SOI substrates for photonic devices. <i>Journal of Applied Physics</i> , 2018, 123,	2.5	5
7	1550-nm Evanescent Hybrid InGaAsP-Si Laser With Buried Ridge Stripe Structure. <i>IEEE Photonics Technology Letters</i> , 2016, 28, 1146-1149.	2.5	4
8	A 1.6- μ m wide tunable distributed Bragg reflector laser diode based on InGaAs/InGaAsP quantum-wells material. <i>Optics Communications</i> , 2021, 497, 127201.	2.1	4
9	A Hybrid Single-Mode Laser Based on Slotted Silicon Waveguides. <i>IEEE Photonics Technology Letters</i> , 2016, , 1-1.	2.5	2
10	Investigation of InGaAs/GaAs Quantum Well Lasers with Slightly Doped Tunnel Junction. <i>Semiconductors</i> , 2018, 52, 2017-2021.	0.5	2
11	A Widely Tunable Three-Section DBR Lasers for Multi-Species Gas Detection. <i>Applied Sciences (Switzerland)</i> , 2021, 11, 2618.	2.5	2
12	Multicore Photonic Complex-Valued Neural Network with Transformation Layer. <i>Photonics</i> , 2022, 9, 384.	2.0	2
13	1060nm high-power broadband InGaAs/GaAs quantum well thyristor-laser., 2015, , .		1
14	A Directional-Emission 1060-nm GaAs/InGaAs Microcylinder Laser. <i>IEEE Photonics Technology Letters</i> , 2015, 27, 569-572.	2.5	1
15	Hybrid Integration of a Tunneling Diode and a 1310 nm DFB Semiconductor Laser., 2018, , .		1
16	1024-channel Passive Optical Phased Array with High Angular Resolution., 2021, , .		1
17	A Silicon Co-Integrated Light Source Module. <i>IEEE Photonics Technology Letters</i> , 2017, 29, 987-990.	2.5	0
18	Demonstration of on-chip mode conversion, multiplexing and demultiplexing using cascaded MMI couplers on InP substrate., 2018, , .		0

#	ARTICLE	IF	CITATIONS
19	Quantum Well Laser-Based Optical Bistable Switching Device. , 2018, , .	0	
20	512-Channel Optical Phased Array with Large Field of View and High Resolution. , 2021, , .	0	
21	Selective Growth of Energy-Band-Controllable $\text{In}_{1-x}\text{Ga}_x\text{AsyP}_{1-y}$ Submicron Wires in V-Shaped Trench on Si. Crystals, 2022, 12, 476.	2.2	0
22	Low fabrication cost wavelength tunable WG-FP hybrid-cavity laser working over $1.7 \frac{1}{4}\text{m}$. Journal of Semiconductors, 2022, 43, 062302.	3.7	0